



GPDP5164

AVALANCHE RECTIFIER DIODE

V_{RRM} 3800 - 4400 - 5000 V
AVERAGE CURRENT 1640 A
SURGE CURRENT 18 kA

BLOCKING CHARACTERISTICS

Characteristic	Conditions	Value
V _{RRM}	Repetitive peak reverse voltage	3800 - 4400 - 5000 V
I _{RRM}	Repetitive peak reverse current, max.	V _{RRM} , single phase, half wave, T _{jmax}
P _{RSM}	Peak reverse power, max	T _{jmax} , t _p = 20μs
		50 kW

FORWARD CHARACTERISTICS

I _{F(AV)}	Average forward current	Sine wave, 180° conduction, T _h = 55°C	1640 A
I _{F(RMS)}	R.M.S. forward current	Sine wave, 180° conduction, Th = 55°C	2575 A
I _{FSM}	Surge forward current	Non rep. half sine wave, 50 Hz, V _R = 0 V, T _j = T _{jmax}	18 kA
I ² t	I ² t for fusing coordination		1620 kA ² s
V _{F(TO)}	Threshold voltage	T _j = T _{jmax}	1.13 V
r _F	Forward slope resistance	T _j = T _{jmax}	0.440 mΩ
V _{FM}	Peak forward voltage, max	Forward current I _F = 4000 A, T _j = 25°C	2.40 V

SWITCHING CHARACTERISTICS

Q _{rr}	R _{reverse recovery charge, typ}	T _j = T _{jmax} , I _F = 2000 A, dI/dt = -5 A/μs	4250 μC
I _{rr}	Reverse recovery current	V _R = 100 V	A
t _{rr}	Reverse recovery time		μs
			V

THERMAL AND MECHANICAL CHARACTERISTICS

R _{th(j-c)}	Thermal resistance (junction to case)	Double side cooled	0.020 °C/W
R _{th(c-h)}	Thermal resistance (case to heatsink)	Double side cooled	0.002 °C/W
T _{jmax}	Max operating junction temperature		160 °C
T _{stg}	Storage temperature		-40 / 160 °C
F	Clamping force ± 10%		22 kN
	Mass		500 g